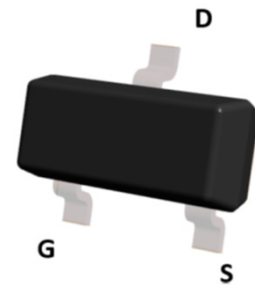
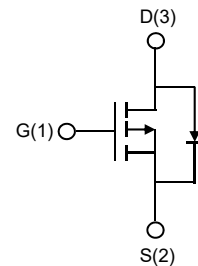
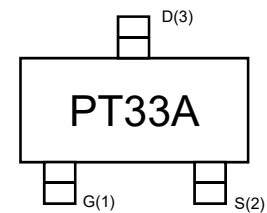


## Description

The MOSFET provide the best combination of fast switching , low on-resistance and cost-effectiveness.

- Trench Power MV MOSFET technology
- Voltage controlled small signal switch
- Low input Capacitance
- Fast Switching Speed
- Low Input / Output Leakage


**Top View**

**Circuit Diagram**

**Marking (Top View)**

### MOSFET Product Summary

$V_{DS}(V)$	$R_{DS(on)}(m\Omega)$	$I_D(A)$
-30	50@ $V_{GS} = -10V$	-3.0
	72@ $V_{GS} = -4.5V$	

## Applications

- Battery operated systems
- Solid-state relays
- Direct logic-level interface: TTL/CMOS

## Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Drain-source Voltage	$V_{DS}$	-30	V
Gate-source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current	$I_D$	-3.0	A
Pulsed Drain Current	$I_{DM}$	-15	A
Total Power Dissipation <sup>1)</sup>	$P_D$	0.78	W
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	°C

## Thermal Resistance

Parameter	Symbol	Min	Typ	Max	Unit
Thermal Resistance, Junction-to-Case <sup>2)</sup>	$R_{\theta JC}$	-	23.6	-	°C/W
Thermal Resistance, Junction-to-Ambient <sup>2)</sup>	$R_{\theta JA}$	-	109	-	°C/W

Notes:

1.  $T_c=124^\circ C$  Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
2. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
<b>OFF Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30V, V_{GS} = 0V$	-	-	-1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1.0	-	-2.4	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -3A$	-	72	90	m $\Omega$
		$V_{GS} = -10V, I_D = -4.2A$	-	50	70	
Gate resistance	$R_g$	$V_{DS}=0V, V_{GS}=0V, f=1MHz$	-	25	-	$\Omega$
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=-1.0A$	-	-0.8	-1.2	V
<b>Dynamic Parameters</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$	-	560	-	pF
Output Capacitance	$C_{oss}$		-	75	-	
Reverse Transfer Capacitance	$C_{rss}$		-	65	-	
<b>Switching Parameters</b>						
Total Gate Charge	$Q_g$	$V_{GS} = -10V, V_{DS} = -15V, I_D = -1.7A$	-	11.2	-	nC
Total Gate Charge	$Q_g$	$V_{GS} = -4.5V, V_{DS} = -15V, I_D = -1.7A$	-	5.7	-	nC
Gate Source Charge	$Q_{gs}$		-	1.4	-	
Gate Drain Charge	$Q_{gd}$		-	2.3	-	
Turn-on Delay Time	$t_{D(on)}$	$V_{GS} = -10V, V_{DS} = -10V, R_G = 6\Omega, R_L = 15\Omega$	-	6.3	-	ns
Turn-on Rise Time	$t_r$		-	19	-	
Turn-off Delay Time	$t_{D(off)}$		-	32	-	
Turn-off Fall Time	$t_f$		-	33	-	

Typical Characteristics

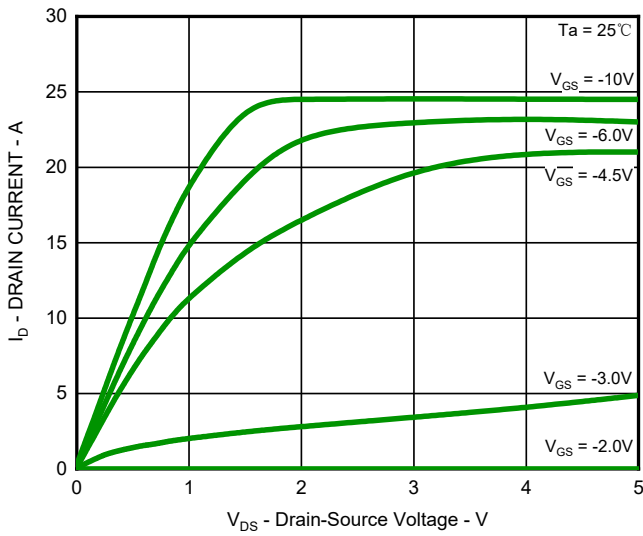


Fig.1 Output Characteristics

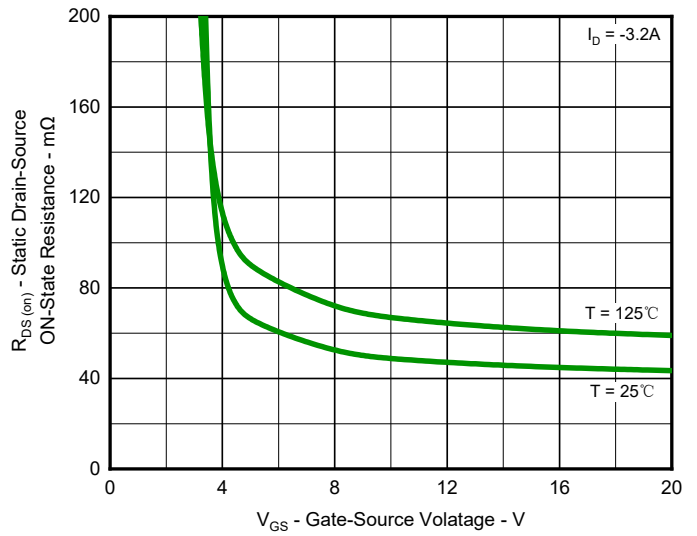


Fig.2 On-Resistance vs. Gate-Source Voltage

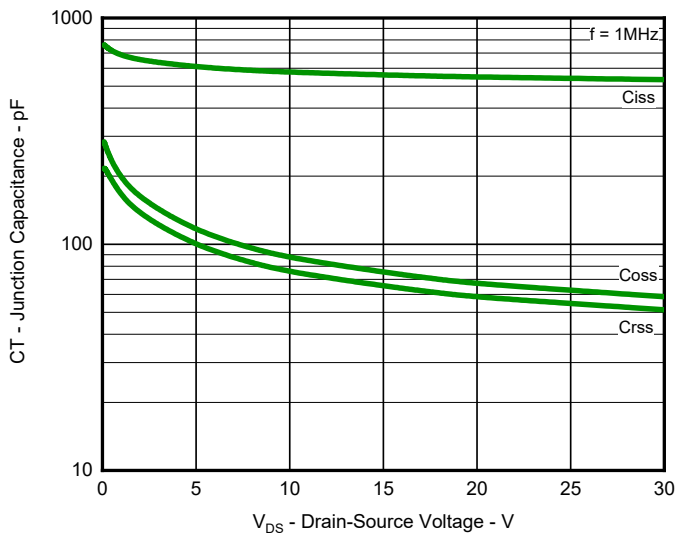


Fig.3 Typical Junction Capacitance

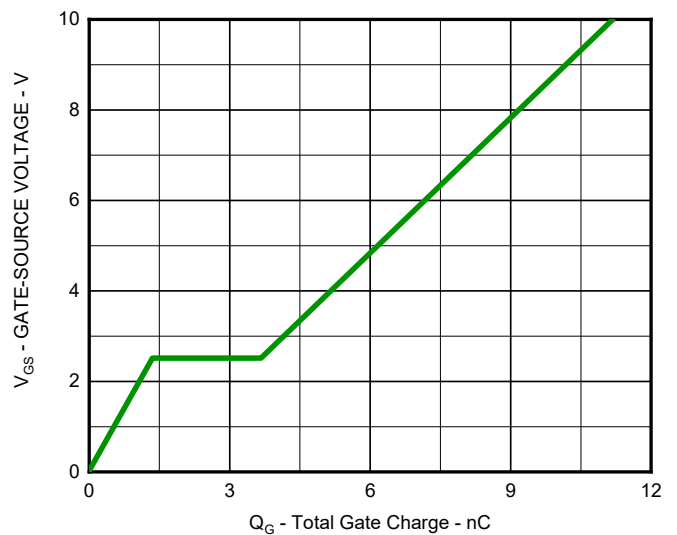


Fig.4 Gate Charge Characteristics

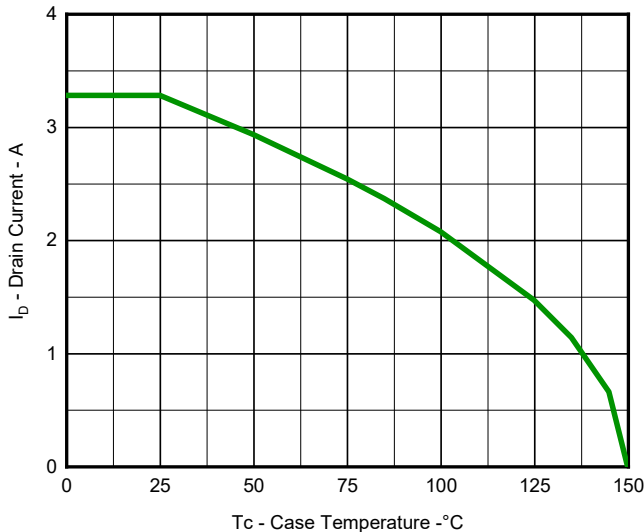


Fig.5 Maximum Drain Current vs. Case Temperature

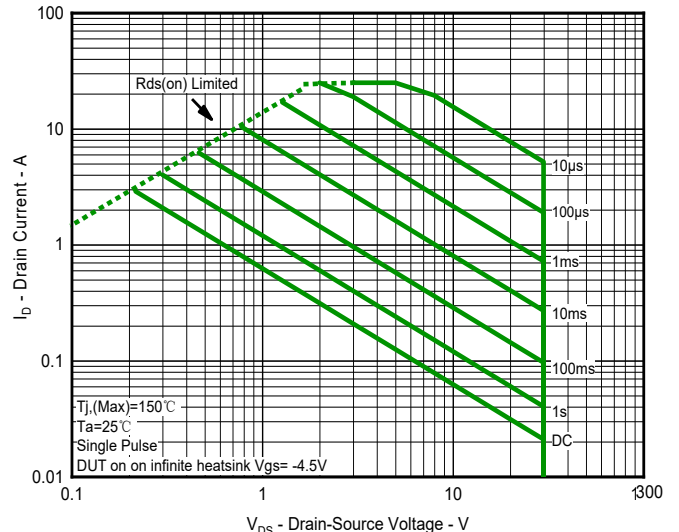


Fig.6 Safe Operation Area

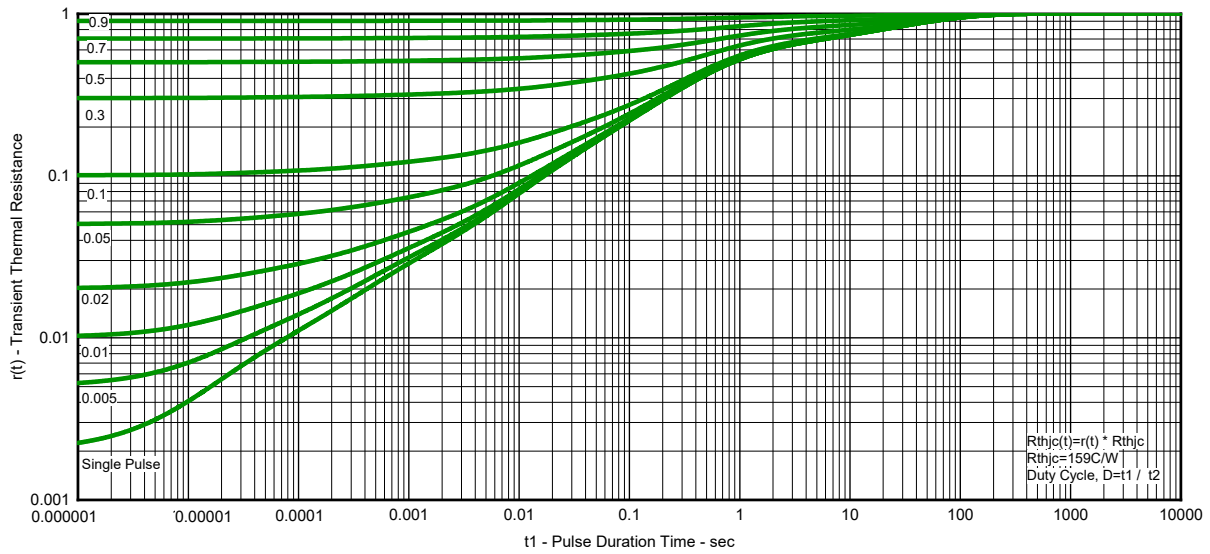
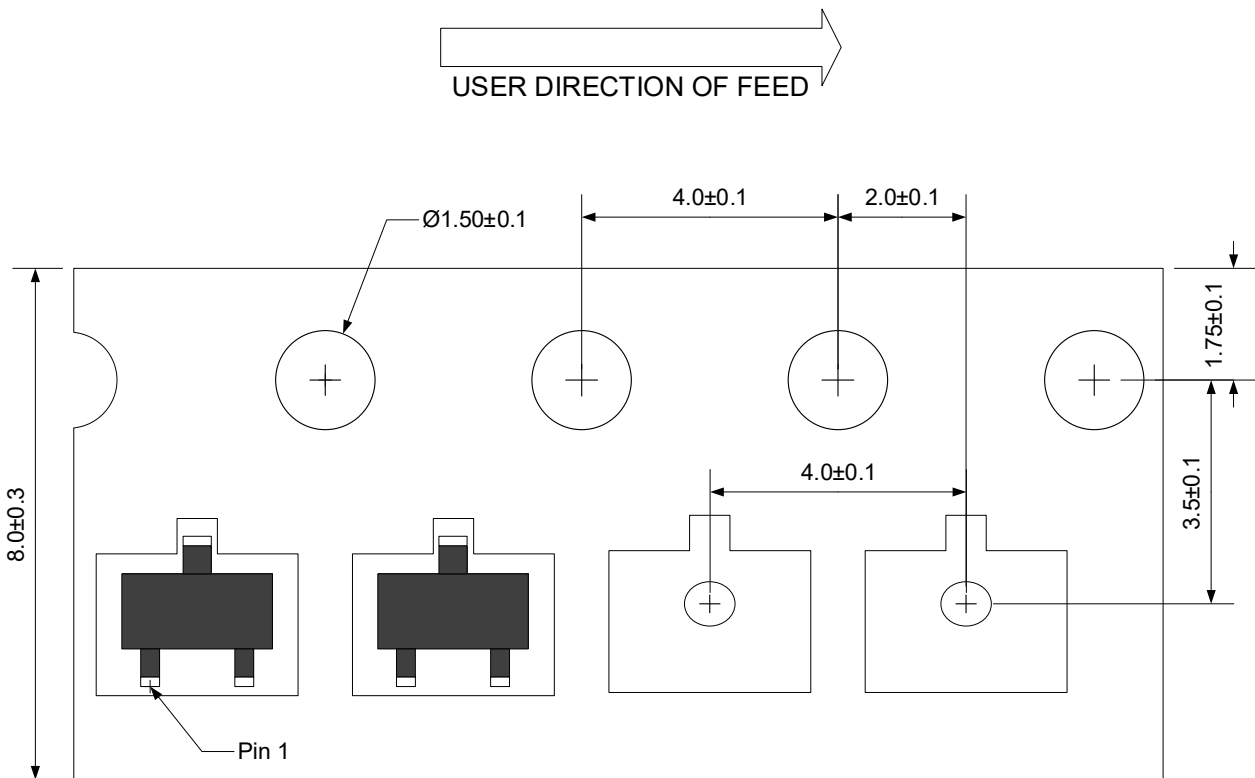


Fig.7 Transient Thermal Resistance

Ordering information

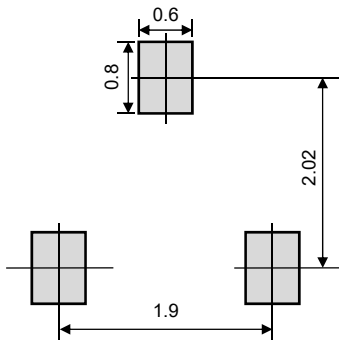
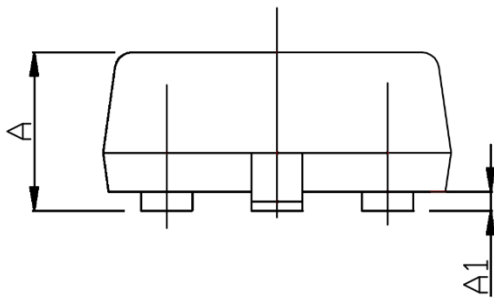
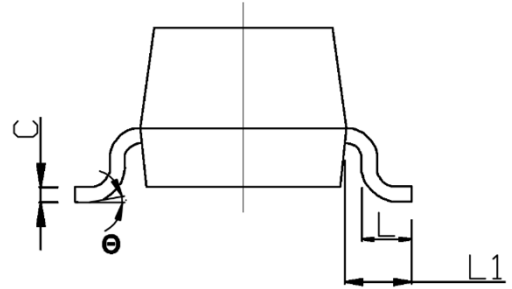
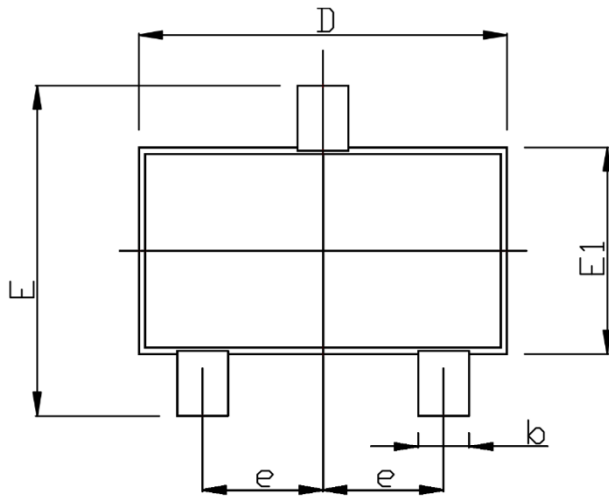
Device	Package	Reel	Shipping
PPMT30V3A	SOT-23 (Pb-Free)	7"	3000 / Tape & Reel

Load with information



Unit:mm

Product dimension (SOT-23)




Suggested PCB Layout

Unit:mm

Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	-	1.35	-	0.053
A1	0.04	0.15	0.002	0.006
b	0.30	0.50	0.012	0.020
c	0.08	0.21	0.003	0.008
D	2.72	3.12	0.107	0.123
E	2.10	2.64	0.083	0.104
E1	1.10	1.50	0.043	0.059
e	0.95 BSC		0.037 BSC	
L	0.20	0.48	0.008	0.019
L1	0.50	0.60	0.020	0.024
$\theta$	0°	8°	0°	8°


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